

Designing Oscillator for an Antenna at $\sim\!\!3.5$ GHz

2896

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Milestones completed so far

- Created test schematic for oscillator using an ideal transistor
- Ran LTSpice Simulations for the ideal version
- Selected an RF transistor with a required performance at the interested frequency
- Ran PSpice Simulations for the same schematic but with non-ideal transistor
- Collected useful data like S-parameters, Z-parameters, Z_{in} and Z_{out} in order to build matching network
- Built matching network for Z_{out} and $Z_{load} = 50 [\Omega]$ at $\sim 3.5 [extit{GHz}]$
- Tested the power output of the circuit for the matching and adjusted the values to maximize power transfer between the DC sources and Z_{load}

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Choosing the BJT

- The transistor needs high-frequency performance, including f_{max} and f_t , well above 3.5[GHz].
- Low parasitic capacitance at collector, base, and emitter terminals is crucial.
- Low noise figure is essential.
- High gain, especially at the operating frequency, is necessary for stable oscillation.
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- Surface mount low voltage silicon NPN RF bipolar transistor
- Transition frequency f_T of 45[GHz]
- High Gain, with $|S_{12}|,\,G_{ma},\,G_{ms}>16[dB]$ at 3.5[GHz] under $V_{ce}=2[V]$
- Low Noise Figure, NF < 1.2[dB] at 3.5[GHz], 2[V], 2[mA]

¹https://www.infineon.com/dgdl/Infineon-BFP520-DS-v02_00-EN.pdf? fileId=5546d462689a790c01690f035fe2391a

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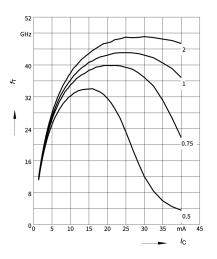
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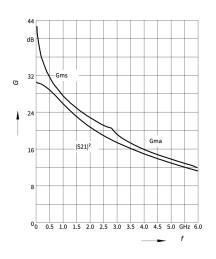
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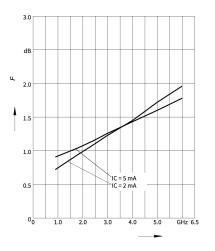
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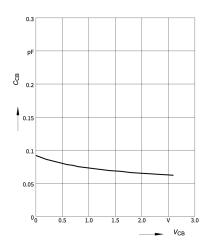
Data from Infenion - 1





Data from Infenion - 2







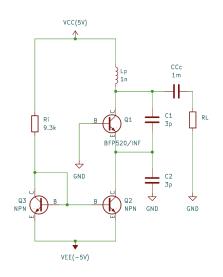
Oscillator Circuit

Collpit's Oscillator

- The circuit was tested with some high impedance load attached
- Values of L_p , C_1 and C_2 were computed using the operating frequency formula

$$f_c pprox rac{1}{2\pi\sqrt{L_prac{C_1C_2}{C_1+C_2}}}$$

 C₁ = C₂ was chosen since it gave the highest oscillation frequency

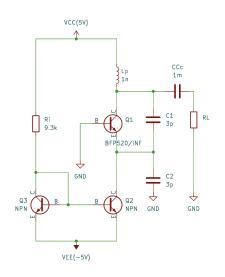


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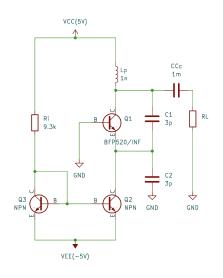


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Ouput Waveform



Choosing a Matching Network

Why Matching Network

- The oscillator we have works for high R_L . Having low R_L , such as $50[\Omega]$ fails to satisfy $g_m R_L^{eff} >> 4$
- We need to design a matching network that converts $R_L = 50[\Omega]$ to the R_L we have in the schematic
- We used a T-Matching network. T-matching is better for matching a load to a source impedance when there's a large disparity because it provides efficient power transfer, minimizes losses, and offers impedance transformation with stability.

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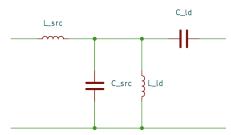
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Matching Network

The following is the matching network used²

$$\begin{cases} L_{src} = \\ C_{src} = \\ L_{ld} = \\ C_{ld} = \end{cases}$$



²Design method in Appendix

S-parameters of the Matching Network

Tested with
$$R_S=1000[\Omega]$$
 and $R_L=50[\Omega]$

Ouput of Oscillator using Matching Network as $50[\Omega]$ load



Efficiency η

Defining η

- Input: $P_{DC} = V_{CC}I_C$
- Output: $P_{ac} = \frac{V_{rms}^2}{R_L}$ where $V_{rms} = \frac{V_{max}}{\sqrt{2}}$ for the output waveform
- Efficiency: $\eta = \frac{P_{ac}}{P_{CD}}^3$

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Calculation of η



- Create an antenna at 3.5[GHz]
- Measure S-parameters of the antenna and of the whole system
- Layout the PCB
- Fabrication and Testing

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Appendix

Proof of operating frequency

BFP520 Spice File

```
*$
.SUBCKT BFP520/INF 200 100 300
L1
          10
              0.47nH
L2
          20
             0.56nH
L3
          30
             0.23nH
C.1
     10
          20
             6.9 fF
C2
             134fF
     20
         30
C3
             136fF
     30
         10
             0.53nH
L4
    10
         100
             0.58nH
15
     20
         200
L6
    30
         300
              0.05nH
Q1
     2 1 3 BFP520
. ENDS
.MODEL BFP520 NPN(
+ IS = 1.5E - 17
                   NF = 1
                                    NR = 1
+ ISE=2.5E-14 NE =2
                                   ISC=2E-14
+ NC =2
               BF =235
                                    BR =1.5
+ VAF=25
                VAR=2
                                   IKF=0.4
+ IKR = 0.01
                  RB =11
                                    RBM=7.5
+ RE = 0.6
                  RC = 7.6
                                   CJE=2.35E-13
+ VJE=0.958
                   MJE = 0.335
                                    CJC=9.3E-14
+ VJC=0.661
                   MJC=0.236
                                    CJS=0
+ V.IS = 0.75
                   MJS=0.333
                                   FC = 0.5
+ XCJC=1
                  TF=1.7E-12
                                   TR=5E-08
+ XTF=10
                   ITF=0.7
                                   VTF=5
+ PTF=50
                   XTB=-0.25
                                    XTI=0.035
+ EG = 1.11)
*$
```

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Calculation of matching network